

# **SBL2030CT - SBL2060CT**

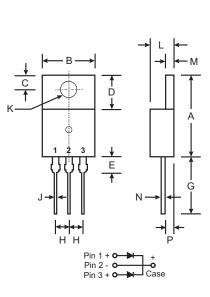
### **20A SCHOTTKY BARRIER RECTIFIER**

#### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Lead Free Finish, RoHS Compliant (Note 3)

#### **Mechanical Data**

- Case: TO-220AB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Polarity: As Marked on Body
- Terminals: Finish Bright Tin. Solderable per MIL-STD-202, Method 208
- Marking: Type Number
- Weight: 2.24 grams (approx.)



TO-220AB							
Dim	Min	Max					
Α	14.48	15.75					
В	10.00	10.40					
С	2.54	3.43					
D	5.90	6.40					
E	2.80	3.93					
G	12.70	14.27					
н	2.40	2.70					
J	0.69	0.93					
к	3.54	3.78					
L	4.07	4.82					
М	1.15	1.39					
N	0.30	0.50					
Р	2.04	2.79					
All Dimensions in mm							

#### Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

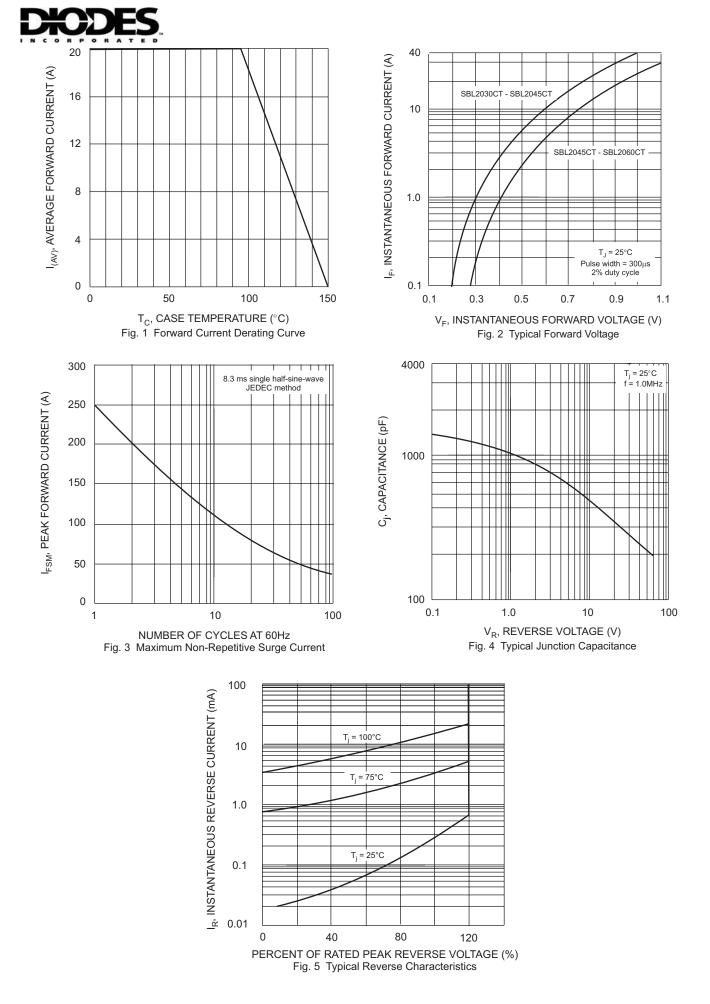
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SBL 2030CT	SBL 2035CT	SBL 2040CT	SBL 2045CT	SBL 2050CT	SBL 2060CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> VR	30	35	40	45	50	60	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	21	24.5	28	31.5	35	42	V
Average Rectified Output Current (Note 1) $@ T_C = 95^{\circ}C$		20					А	
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		250					А	
Forward Voltage Drop @ $I_F = 10A$ , $T_C = 25^{\circ}C$		0.55 0.75				75	V	
$\begin{tabular}{lllllllllllllllllllllllllllllllllll$		1.0 50					mA	
Typical Junction Capacitance (Note 2)		650					pF	
Typical Thermal Resistance Junction to Case (Note 1)		2.8					°C/W	
Operating and Storage Temperature Range		-65 to +150				°C		

Notes: 1. Thermal resistance junction to case mounted on heatsink.

2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V DC.

3. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.





## Ordering Information (Note 4)

Device	Packaging	Shipping
SBL20xxCT*	TO-220AB	50/Tube

\* xx = Device type, e.g. SBL2045CT

Notes: 4. For packaging details, visit our website at http://www.diodes.com/datasheets/ap02008.pdf.